

0.5-18 GHz and 2-18 GHz

Super-Slim High Performance Drop-In PIN Switches



- Reflective and Absorptive
- SPST thru SP6T and Transfer (Standard)
- High Speed
- High Isolation – up to 80 dB
- Low Insertion Loss
- Drop-In Applications
- Integral TTL Drivers
- Hermetically Sealed
- Full MIL Specifications

Description

The super-slim series of broadband, hermetically sealed switches offers fast switching speed and low insertion loss in very compact packages. Both 0.5 to 18 GHz and 2 to 18 GHz models are available. The switches are gold plated and have removable SMA connectors for use in drop-in applications. Superior RF performance is achieved over the entire bandwidth due to the use of selected PIN diodes and optimum RF circuit designs.

All models include integral drivers with reverse voltage protection. The drivers are TTL compatible and are tailored to each RF circuit to give optimum switching performance.

The small size, high speed, broad bandwidth and low insertion loss make these switches ideal for EW systems, automatic test equipment and simulators.

Specifications

Reflective Switches, SMA (F), 0.5 to 18 GHz

MODEL	TYPE	SWITCHING TIME MODULATION (ns)	BAND SEGMENTS (GHz)	INSERTION LOSS (dB max.)	VSWR (max.)	ISOLATION (dB min.)	POWER HANDLING (mW)	POWER SUPPLY REQUIREMENTS				
								mA @+5 V	mA @-12 V			
SS212DHS	SPST	15	0.5-2	1.1	1.6	70	200	50	50			
			2-4	1.3	1.7	70						
			4-8	1.6	1.8	70						
			8-12	2.1	1.9	70						
			12-18	2.6	2.0	70						
SS122DHS	SP2T	20	0.5-2	1.5	1.8	70	502	8Sp242	EMC	S4DC	T1322 Tm	(2-4)
			2-4	1.5	1.9							
			4-8	2.0	1.9							
			8-12	2.4	70							
			12-18	2.9								

Specifications

Reflective Switches, SMA (F), 2 to 18 GHz

MODEL	TYPE	SWITCHING TIME MODULATION (ns)	BAND SEGMENTS (GHz)	INSERTION LOSS (dB max.)	VSWR (max.)	ISOLATION (dB min.)	POWER HANDLING (mW)	POWER SUPPLY REQUIREMENTS	
								mA @+5 V	mA @-12 V
SS213DHS	SPST	15	2-4	1.2	1.8	50	500	50	50
			4-8	1.4	1.9	65			
			8-12	1.9	1.9	60			
			12-18	2.4	2.0	60			
SS213DHS-80	SPST	15	2-4						
			4-8						

Absorptive Switches, SMA (F), 2 to 18 GHz

MODEL	TYPE	SWITCHING TIME MODULATION (ns)	BAND SEGMENTS (GHz)	INSERTION LOSS (dB max.)	VSWR (max.)	ISOLATION (dB min.)	POWER HANDLING (mW)	POWER SUPPLY REQUIREMENTS	
								mA @+5 V	mA @-12 V
SS213BDHTS	SPST	20	2-4	1.5	1.9	65	200	40	60
		20	4-8	1.7	1.9	60			
		20	8-12	2.1	1.9	55			
		25	12-16	2.5	2.0	50			
		25	16-18	2.5	2.0	50			
SS123BDHTS	SP2T	20	2-4	1.5	1.9	65	200	40	60
		20	4-8	1.7	1.9	60			
		20	8-12	2.1	1.9	55			
		25	12-16	2.5	2.0	50			
		25	16-18	2.5	2.0	50			

Electrical Specifications

TTL CONTROL LOGIC

Logic 0 (0-0.8 V, 1.6 mA max. sink @0.4 V) = Insertion Loss
Logic 1 (2.0-5.5 V, 40 μ A max. source @2.4 V) = Isolation

FORTRANSFER SWITCH (XSS323CDHS)

Logic 0: J1-J4 and J2-J3 at Insertion Loss
Logic 1: J1-J2 and J4-J3 at Insertion Loss

SWITCHING TIME

T on = 50% TTL to 90% of RF voltage
T off = 50% TTL to 10% of RF voltage

SWITCHING RATE

5 MHz max. PPF @50% duty cycle

DRIVER

Reverse voltage protected

SURVIVAL POWER at 25°C (Cold Switching)

1.0 W CW, 20W Peak (1 μ s max. pulse width, 5% duty cycle)
Derate linearly to 50% at +95°C

Environmental Specifications

TEMPERATURE

Operating -54°C to +95°C
Storage -65°C to +125°C

HUMIDITY

Per MIL-STD-202F, method 103B, condition B
(96 hours at 95% RH.)

SHOCK

Per MIL-STD-202F, method 213B, condition B
(75 G, 6 ms)

ALTITUDE

Per MIL-STD-202F, method 105C, condition B
(50,000 feet)

VIBRATION

Per MIL-STD-202F, method 204D, condition B
(.06" double amplitude or 15 G, whichever is less)

THERMAL SHOCK

Per MIL-STD-202F, method 107D, condition A (5 cycles)

Options

- Very Low Loss Video Leakage
- Inverted TTL Logic Control
- BCD Decoder Driver
- Package Configuration
- Over Voltage Protection

Outline Drawings



